

Product Summary

Device	BVDSS	RDS(ON) max	Id max Ta = +25°C
		34mΩ @ V _{GS} = 4.5V	5.1A
Q1	12V	40mΩ @ VGS = 2.5V	4.7A
N-Channel		4.2A	
		70mΩ @ VGS = 1.5V	3.6A
		59mΩ @ V _{GS} = -4.5V	-3.9A
Q2	101/	81mΩ @ V _{GS} = -2.5V	-3.3A
P-Channel	-12V	$115m\Omega @ V_{GS} = -1.8V$	-2.8A
		215mΩ @ V _{GS} = -1.5V	-2.0A

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Load Switch
- Power Management Functions
- Portable Power Adaptors

Features

- Low On-Resistance
- Low Input Capacitance
- Low Profile, 0.6mm Max Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

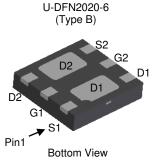
https://www.diodes.com/quality/product-definitions/

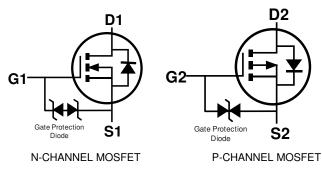
 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMC1030UFDBQ</u>)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208@
- Terminals Connections: See Diagram Below
- Weight: 0.0065 grams (Approximate)







Internal Schematic

Ordering Information (Note 4)

-	-	
Part Number	Case	Packaging
DMC1030UFDB -7	U-DFN2020-6 (Type B)	3000/Tape & Reel
DMC1030UFDB -13	U-DFN2020-6 (Type B)	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

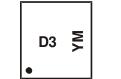
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1



D3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020)M = Month (ex: 9 = September)

Date Code Key

Year	2014		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	В		Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



D3 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key												
Year	2014		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	4		0	1	2	3	4	5	6	7	8	9
Week		1	-26			27	-52			5	3	
Code		1	A-Z			a	-Z			Z	<u> </u>	
Internal Code	Sur	1 I	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	1	N	Х		Y		Ζ



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Q1 N-CHANNEL	Q2 P-CHANNEL	Unit
Drain-Source Voltage			VDSS	12	-12	V
Gate-Source Voltage			Vgss	±8	±8	V
Continuous Drain Current (Note 5) N-Channel: V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	lo	5.1 4.1	-3.9 -3.1	А
P-Channel: $V_{GS} = -4.5V$	t < 5s	T _A = +25°C T _A = +70°C	lD	6.6 5.3	-5.0 -4.0	А
Maximum Continuous Body Diode Forward Cur	ls	2	-1.7	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle =	ldм	35	-25	А		

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	Steady State	Da	1.36	W	
Total Fower Dissipation (Note 5)	t < 5s	PD	1.89	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D. u	92		
memai resistance, junction to Ambient (Note 5)	t < 5s	Reja	66	°C/W	
Thermal Resistance, Junction to Case (Note 5)	Rejc	18			
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

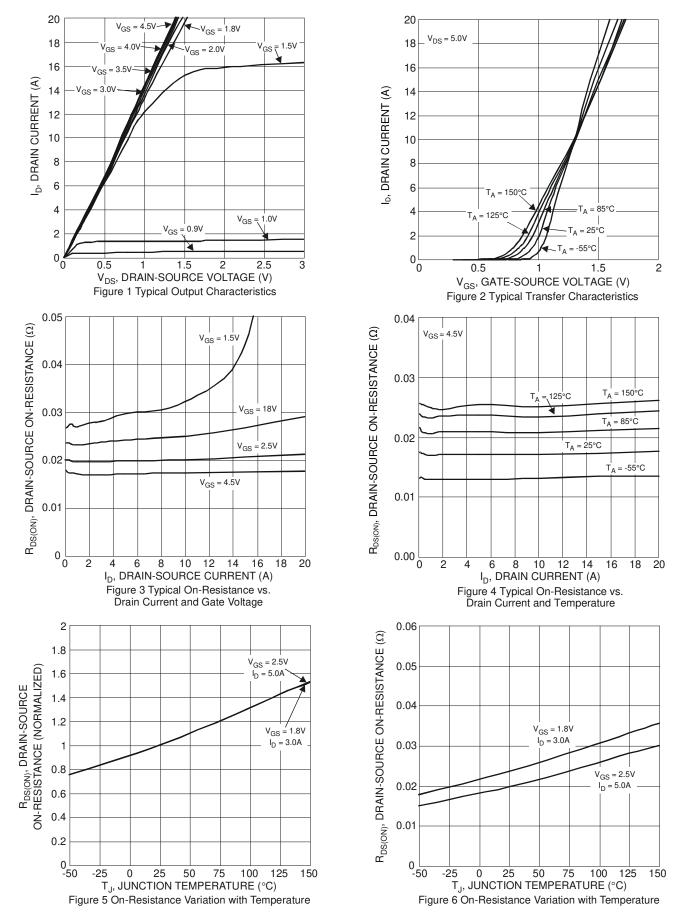
Electrical Characteristics Q1 N-CHANNEL (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	,					
Drain-Source Breakdown Voltage	BVDSS	12		—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	-	_	1.0	μA	$V_{DS} = 12V, V_{GS} = 0V$
Gate-Source Leakage	Igss			±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)	•					·
Gate Threshold Voltage	VGS(TH)	0.4	—	1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			17	34		VGS = 4.5V, ID = 4.6A
Static Drain-Source On-Resistance	Provenu	_	20	40	mΩ	$V_{GS} = 2.5V, I_D = 4.2A$
	RDS(ON)	_	24	50	11152	$V_{GS} = 1.8V, I_D = 3.8A$
		_	28	70		VGS = 1.5V, ID = 1.5A
Diode Forward Voltage	Vsd	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 4.8A$
DYNAMIC CHARACTERISTICS (Note 7)				•	•	·
Input Capacitance	Ciss	_	1003	—	pF	
Output Capacitance	Coss	_	132	—	pF	VDS = 6V, VGS = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	-	115	—	pF	
Gate Resistance	Rg	-	11.3	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)		-	12.2	_	nC	
Total Gate Charge (V _{GS} = 8V)	Qg	_	23.1	—	nC	V _{DS} = 10V, I _D = 6.8A
Gate-Source Charge	Qgs	-	1.3	—	nC	$v_{DS} = 10v, ID = 0.6A$
Gate-Drain Charge	Q _{gd}	-	1.5	—	nC	
Turn-On Delay Time	td(ON)	_	4.4	_	ns	
Turn-On Rise Time	tR		7.4	—	ns	$V_{DD} = 6V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(OFF)	_	18.8	_	ns	$R_L = 1.1\Omega, R_G = 1\Omega$
Turn-Off Fall Time	tF	_	4.9	_	ns	7
Body Diode Reverse Recovery Time	trr	_	7.6	_	ns	Is = 5.4A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	QRR	_	0.9	_	nC	Is = 5.4A, dl/dt = 100A/µs

Notes:

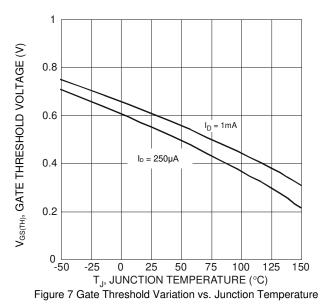
Device mounted on 1" × 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.







DMC1030UFDB



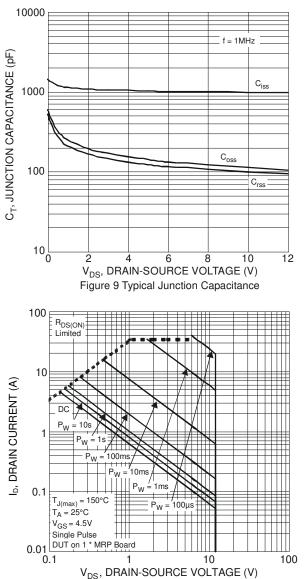
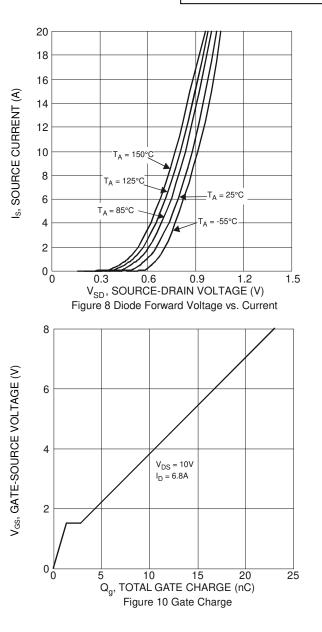


Figure 11 SOA Safe Operation Area

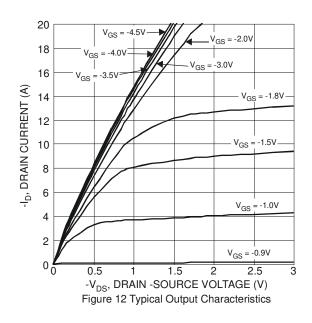


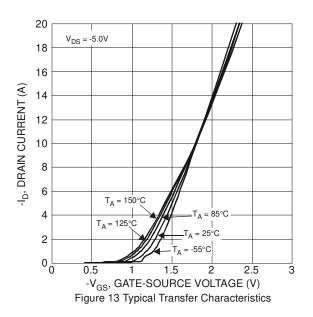


Electrical Characteristics Q2 P-CHANNEL (@ TA = +25°C, unless otherwise specified.)

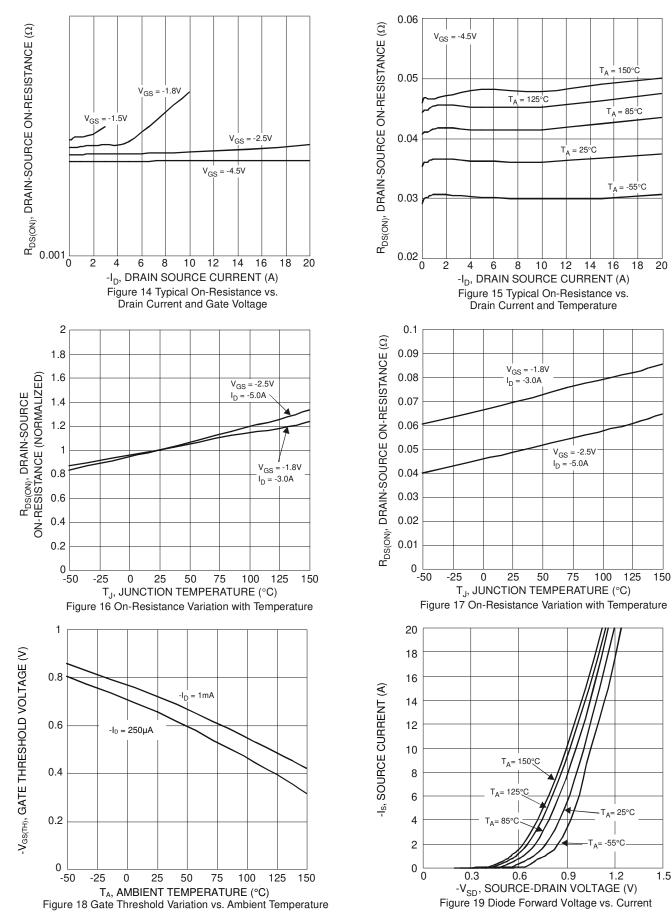
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-12	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS		_	-1.0	μA	V _{DS} = -12V, V _{GS} = 0V
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)	•				•	
Gate Threshold Voltage	VGS(TH)	-0.4	_	-1	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
			37	59		V _{GS} = -4.5V, I _D = -3.6A
Static Drain-Source On-Resistance	Desser		48	81	mΩ	V _{GS} = -2.5V, I _D = -3.1A
Static Drain-Source On-Resistance	RDS(ON)		69	115	1112	$V_{GS} = -1.8V, I_D = -2.6A$
		_	88	215		$V_{GS} = -1.5V, I_D = -0.5A$
Diode Forward Voltage	V _{SD}		-0.7	-1.2	V	V _{GS} = 0V, I _S = -3.7A
DYNAMIC CHARACTERISTICS (Note 7)			•		•	
Input Capacitance	Ciss	_	1028	_	pF	
Output Capacitance	Coss	_	285	_	pF	VDS = -6V, VGS = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	254	_	pF	
Gate Resistance	Rg	_	19.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	0		13	_	nC	
Total Gate Charge (V _{GS} = -8V)	Qg		20.8	_	nC	Vps = -10V. lp = -4.7A
Gate-Source Charge	Qgs		1.8	-	nC	VDS = -10V, 1D = -4.7A
Gate-Drain Charge	Q _{gd}		4.5	-	nC	7
Turn-On Delay Time	tD(ON)		5.6		ns	
Turn-On Rise Time	tR		12.8		ns	$V_{DD} = -6V, V_{GS} = -4.5V,$
Turn-Off Delay Time	tD(OFF)	_	30.7		ns	R _L = 1.6Ω, R _G = 1Ω
Turn-Off Fall Time	tF	_	25.4	_	ns	1
Body Diode Reverse Recovery Time	trr	_	31.6	_	ns	Is = -3.6A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	Qrr	_	7.8	_	nC	Is = -3.6A, dl/dt = 100A/µs

Notes: 6. Short duration pulse test used to minimize self-heating effect. 7. Guaranteed by design. Not subject to product testing.





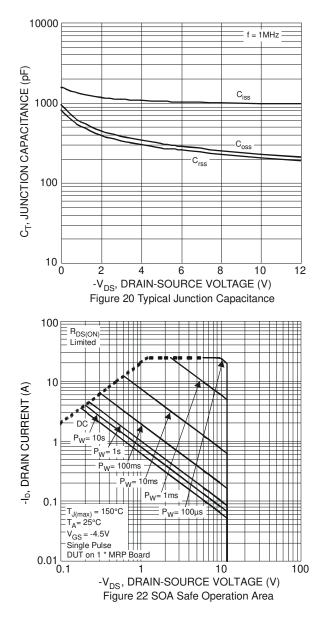


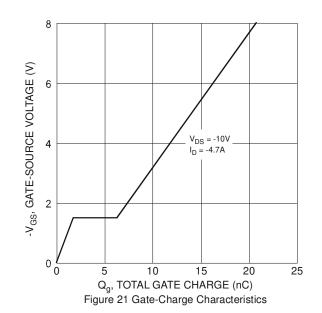


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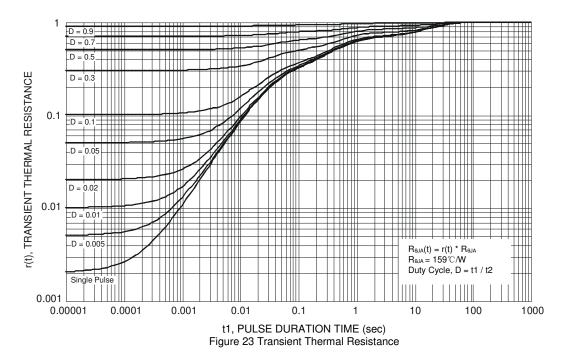
DMC1030UFDB







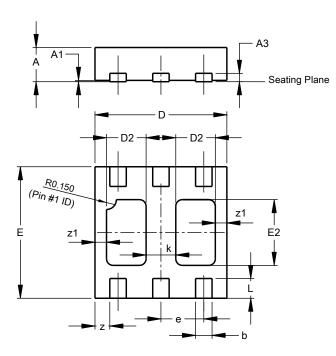






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

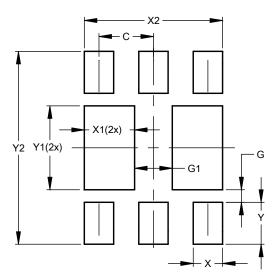


1									
	U-DFN2020-6								
	Туре В								
Dim	Min	Max	Тур						
Α	0.545	0.605	0.575						
A1	0.00	0.05	0.02						
A3	-	-	0.13						
b	0.20	0.30	0.25						
D	1.95	2.075	2.00						
D2	0.50	0.70	0.60						
е	-	-	0.65						
E	1.95	2.075	2.00						
E2	0.90	1.10	1.00						
k	-	-	0.45						
L	0.25	0.35	0.30						
z	-	-	0.225						
z1	-	-	0.175						
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type B)



Dimensions	Value (in mm)
С	0.650
G	0.150
G1	0.450
Х	0.350
X1	0.600
X2	1.650
Y	0.500
Y1	1.000
Y2	2.300

U-DFN2020-6 (Type B)



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